RFPT700



SMD Low Acceleration Sensitivity TCXO / TCVCXO.

SPECIFICATION REFERENCES

A series of surface mountable Temperature Compensated Voltage Controlled Crystal Oscillators (TCVCXOs) for applications where phase noise performance under vibration is critical.



Product description

The RFPT700 TCVCXO uses Rakon's proprietary ASIC 'Pluto™', a single chip oscillator with analogue compensation circuit, and a patented crystal resonator design, resulting in high stability over a wide temperature range paired with typically 0.2ppb/g acceleration sensitivity.

Applications

- Communications
- Avionics
- Guidance
- Military

Features

1.0

Specifications

| Line | Parameter | Description | | | | | |
|------|---|--|------------|--------|--|--|--|
| 1.1 | Description | n RFPT700 | | | | | |
| 1.2 | Rakon part number | | | | | | |
| 1.3 | RoHS compliant | Yes (non-RoHS version available upon request) | | | | | |
| 1.4 | Package size | 14.7 x 9.2 x 4.35 mm (max) | | | | | |
| | | | | | | | |
| 2.0 | FREQUENCY CHARACTER | USTICS | | | | | |
| Line | Parameter | Test Condition | Value | Unit | | | |
| 2.1 | Frequency range | | 10 to 30 | MHz | | | |
| 2.2 | Frequency calibration | At 25°C±2°C, at time of shipment, reference to nominal frequency | ±1 max | ppm | | | |
| 2.3 | Reflow shift | After 1 hour recovery at 25°C | ±1 max | ppm | | | |
| 2.4 | Frequency stability over temperature | Reference to (Fmax + Fmin)/2 (note 1) | ±0.2 to 5 | ppm | | | |
| 2.5 | Temperature range | Operating temperature range over which temperature stability is measured (note 2) | -55 to 105 | °C | | | |
| 2.6 | Slope | Temperature ramp 1°C/minute | 20 to 200 | ppb/°C | | | |
| 2.7 | Supply voltage stability, HCMOS output | ±5% variation, reference to frequency at nominal supply voltage, typically less than | ±0.2 | ppm | | | |
| 2.8 | Supply voltage stability, clipped sinewave output | $\pm 5\%$ variation, reference to frequency at nominal supply voltage, typical less than | ±0.1 | ppm | | | |
| 2.9 | Load sensitivity, HCMOS output | $\pm 5 pF$ variation, reference to frequency at 15pF load, typically less than | ±0.2 | ppm | | | |
| 2.10 | Load sensitivity, Clipped Sinewave Output | $\pm 10\%$ variation, reference to frequency at 10k//10pF, typically less than | ±0.1 | ppm | | | |
| 2.11 | Long term stability | first year, ≤ 26MHz | ±1 max | ppm | | | |
| 2.12 | Long term stability | first year, > 26MHz | ±2 max | ppm | | | |
| 2.13 | Long term stability | 10 years, ≤ 26MHz | ±3 max | ppm | | | |
| 2.14 | Long term stability | 10 years, > 26MHz | ±5 max | ppm | | | |
| 2.15 | Acceleration sensitivity | Gamma Vector over operating temperature range (typically 0.2ppb/g) | 0.5 max | ppb/g | | | |

| 3.0 | POWER SUPPLY | | | |
|------|-------------------------------|---|------------|------|
| Line | Parameter | Test Condition | Value | Unit |
| 3.1 | Supply voltage | Standard supply voltages: 3.3 and 5.0V ($\pm 5\%$), other values available upon request. | 2.5 to 5.7 | V |
| 3.2 | Current HCMOS | typically: $1+frequency(MHz)*supply(V)*\{load(pF)+15\}*10^{-3}mA$ e.g 20MHz, 5V, 15pF = 4mA | | mA |
| 3.3 | Current Clipped Sinewave | typically: 1+frequency(MHz)*1.2*{load(pF) +30}*10-3mA | | mA |
| 4.0 | OSCILLATOR OUTPUT H | CMOS (optional) - note 3 | | |
| Line | Parameter | Test Condition | Value | Unit |
| 4.1 | Output waveform | HCMOS | | |
| 4.2 | Output voltage level low | | 0.1 max | Vs |
| 4.3 | Output voltage level high | | 0.9 min | Vs |
| 4.4 | Rise and fall times | Measured with Vcc = 3.3V | 8 max | ns |
| 4.5 | Rise and fall times | Measured with Vcc = 5.0V | 7 max | ns |
| 4.6 | Duty cycle | Measured at 50% level | 45 to 55 | % |
| 4.7 | Load | | 15 | pF |
| 5.0 | OSCILLATOR OUTPUT CI | IPPED SINEWAVE (optional) - note 3 | | |
| Line | Parameter | Test Condition | Value | Unit |
| 5.1 | Output waveform | Clipped sinewave, DC-coupled | | |
| 5.2 | Output voltage level | Peak to peak voltage | 0.8 min | V |
| 5.3 | Output load resistance | | 10 | kΩ |
| 5.4 | Output load capacitance | | 10 | pF |
| 6.0 | FREQUENCY ADJUSTMEN | NT (optional) | | |
| Line | Parameter | Test Condition | Value | Unit |
| 6.1 | Control Voltage Range | Vc | 0.5 to 2.5 | V |
| 6.2 | Frequency Adjustment Range | frequency ≤ 26MHz | ±5 min | ppm |
| 6.3 | Frequency Adjustment Range | frequency > 26MHz | ±7 min | ppm |

| 7.0 | DUACE NOICE | | | | | |
|-------------|--|---|-----------------|-----------|--|--|
| 7.0 | PHASE NOISE | Test Condition | \ | 11-24 | | |
| Line | Parameter | Test Condition | Value | Unit | | |
| 7.1 | SSB phase noise power density at 1Hz offset | Typical value for a 20MHz Clipped sine wave oscillator at 25°C | -63 | dBc/Hz | | |
| 7.2 | SSB phase noise power density at 10Hz offset | Typical value for a 20MHz Clipped sine wave oscillator at 25°C | -93 | dBc/Hz | | |
| 7.3 | SSB phase noise power density at 100Hz offset | Typical value for a 20MHz Clipped sine wave oscillator at 25°C | -104 | dBc/Hz | | |
| 7.4 | SSB phase noise power density at 1kHz offset | Typical value for a 20MHz Clipped sine wave oscillator at 25°C | -128 | dBc/Hz | | |
| 7.5 | SSB phase noise power density at 10kHz offset | Typical value for a 20MHz Clipped sine wave oscillator at 25°C | -136 | dBc/Hz | | |
| 7.6 | SSB phase noise power density at 100kHz offset | Typical value for a 20MHz Clipped sine wave oscillator at 25°C | -140 | dBc/Hz | | |
| 7.7 | SSB phase noise power density at 1MHz offset | Typical value for a 20MHz Clipped sine wave oscillator at 25°C | -143 | dBc/Hz | | |
| 7.8 | Note | Low phase noise option available with HCMOS output - consult sales office | | | | |
| 8.0 | ENVIRONMENTAL INFOR | RMATION | | | | |
| Line | Parameter Description | | | | | |
| 8.1 | Storage temperature | -55°C to 125°C | | | | |
| 8.2 | Acceleration Steady IEC 60068-2-7 test Ga, 5000g, 10s (at peak acceleration), Y-axis only State | | | | | |
| 8.3 | Vibration | IEC 60068-2-6, test Fc: 10-60Hz 0.75mm displacement, 60-500Hz 200m/s^2 (20gn) acceleration, 1.5 hours in each of three mutually perpendicular axes at 1 octave per minute. | | | | |
| 8.4 | Mechanical Shock | IEC 60068-2-27, test Ea; 1000 m/s^2 (100gn) acceleration for 6ms, half sine pulse, 3 shocks in each direction along three mutually perpendicular axes (18 shocks total) | | | | |
| 8.5 | RoHS | Parts are fully compliant with the European Union directive 2002/95/EC on the restriction of the use of certain hazardous substances in electrical and electronic equipment. Note parts are suitable for assembly using both Lead-free solders and Tin/Lead solders. Non-RoHS version available on request. | | | | |
| 8.6 | Marking | Laser Marked | | | | |
| 0.0 | MANUEACTURING INFO | PMATION | | | | |
| 9.0 | MANUFACTURING INFOR | | | | | |
| Line 9.1 | | Description See reflow profile diagram. Solderability: MIL-STD-202, method 208, category 3 | | | | |
| | Reflow Soldering | , | , category 3 | | | |
| 9.2 | Packaging description | Quantities ≥ 100 pieces will be supplied on tape & reel | | | | |
| 10.0 | SPECIFICATION NOTES | | | | | |
| Line | Parameter | Description | | | | |
| 10.1 | Note 1 Availability of stability depends on temperature range - not all combinations may be possible - please check with our sales office. | | | | | |
| 10.2 | Note 2 | Availability of temperature range -55 to 105°C depends on nominal fi with our sales office. | requency - plea | ase check | | |
| 10.3 | Note 3 | ACMOS / pure sine wave output available upon request | | | | |

11.0 PIN CONNECTIONS Line Parameter Description 11.1 Pin 1 Control Voltage (Vc) OR Do not connect (depending on option selected) Not connected 11.2 Pin 2 11.3 Pin 3 GND 11.4 Pin 4 Output 11.5 Pin 5 Not connected 11.6 Pin 6 Supply Voltage (Vs) 12.0 **MARKING** Line Parameter Description 12.1 Marking includes 12.2 rakon 12.3 Part Number (Exxxx) 12.4 Frequency (MHz) 12.5 Pad 1 identifier (indent) 12.6 Device date / location code 13.0 **DISCLAIMER**

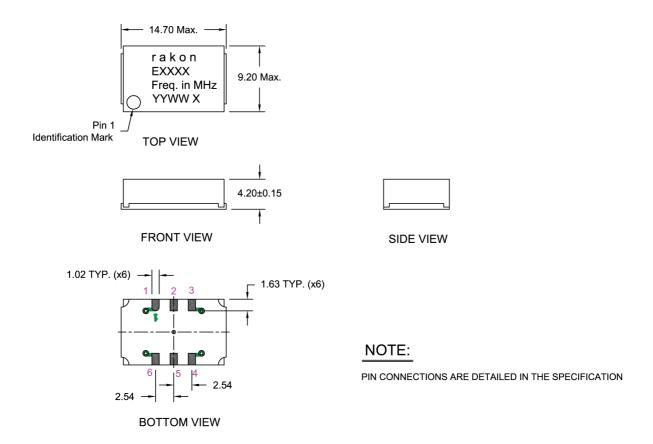
Description Line Parameter

Disclaimer "Samples supplied according to this specification are supplied from our development or pre-13.1 production programme and as such are not qualification approved products. No condition, warranty or representation regarding quality, suitability, performance, life or continuation of supply is given or implied and Guarantee in clause 6.1 of our standard Conditions of Sale is not applicable. The right is reserved to change the design or specification or cease supply

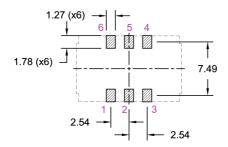
without notice." RAKON UK Limited

Drawing Name: RFPT700 Model Drawing

MODEL OUTLINE



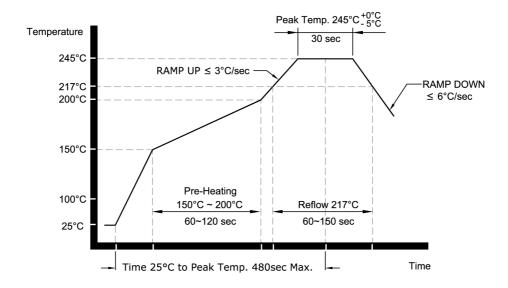
RECOMMENDED PAD LAYOUT (Top View)



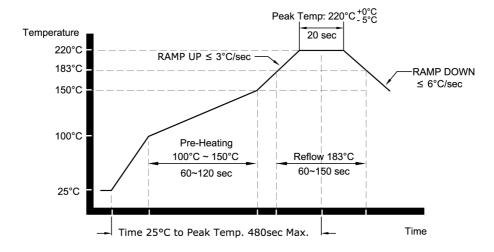
| TITLE: RFPT700 MODEL | FILENAME: | CAT637 | TOLEF | RANCES: | |
|----------------------|-------------|-----------|-------------|--------------|----------------------|
| RELATED DRAWINGS: | REVISION: | В | X.X | = ±0.2 | |
| | DATE: | 14-Mar-12 | X.XX | $= \pm 0.10$ | rakon |
| | SCALE: | 2:1 | X.XXX X° | . = = | |
| | Millimetres | | Hole | = | © 2009 Rakon Limited |

Drawing Name: Pluto USTCXO Reflow

Pb-FREE REFLOW SOLDERING PROFILE*



Sn-Pb EUTECTIC REFLOW SOLDERING PROFILE*



NOTE:

THE PROFILES WERE USED DURING THE QULIFICATION TESTING OF THE PRODUCT AND THEREFORE REPRESENT WORST CASE CONDITIONS. THEY ARE NOT RECOMMENDED FOR USE BY THE CUSTOMER IN THE ACTUAL ASSEMBLY OF THESE PARTS.

| TITLE: PLUTO USTCXO REFLOW | FILENAME: CAT640 | |
|----------------------------|------------------|----------------------|
| RELATED DRAWINGS: | REVISION: A | |
| | DATE: 03-Oct-11 | rakon |
| | SCALE: NTS | |
| | Millimetres | © 2009 Rakon Limited |